

Notes:

 $R_{\theta JA}$

1: Current is limited by bondwire configuration.

2: Starting $T_J = 25^{\circ}$ C, L = 0.6mH, $I_{AS} = 12A$, $V_{DD} = 40V$ during inductor charging and $V_{DD} = 0V$ during time in avalanche.

3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

(Note 3)

Package Marking and Ordering Information

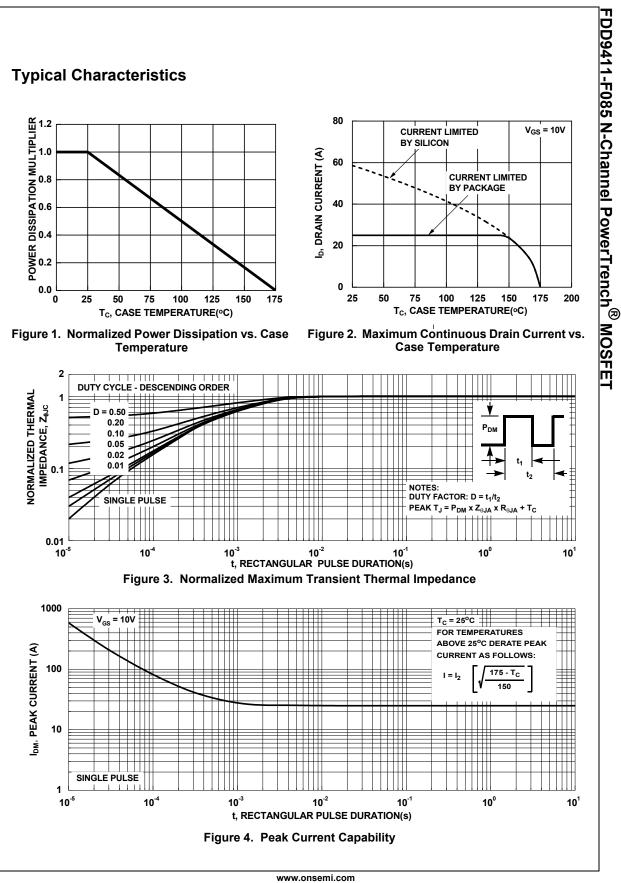
Maximum Thermal Resistance, Junction to Ambient

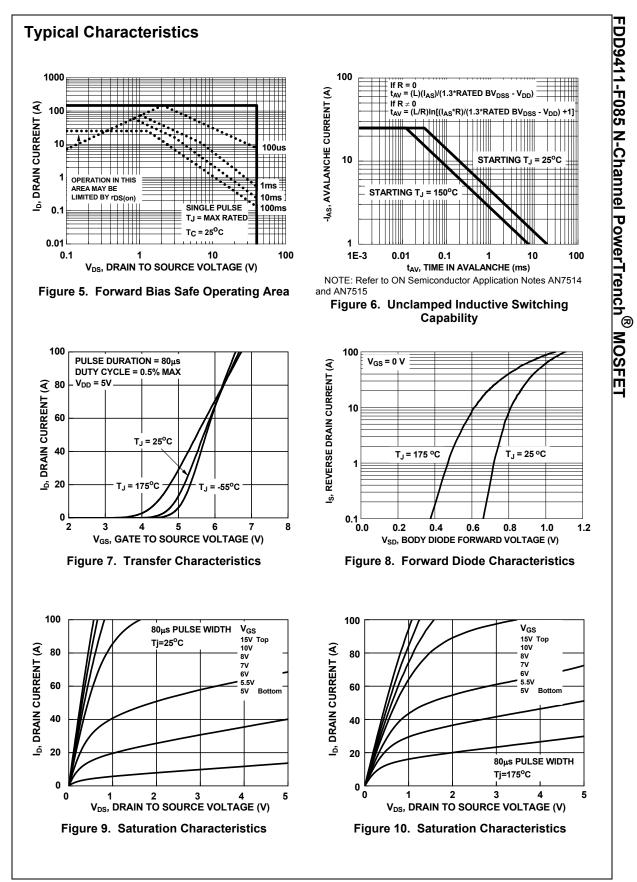
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD9411	FDD9411-F085	D-PAK(TO-252)	13"	16mm	2500units

°C/W

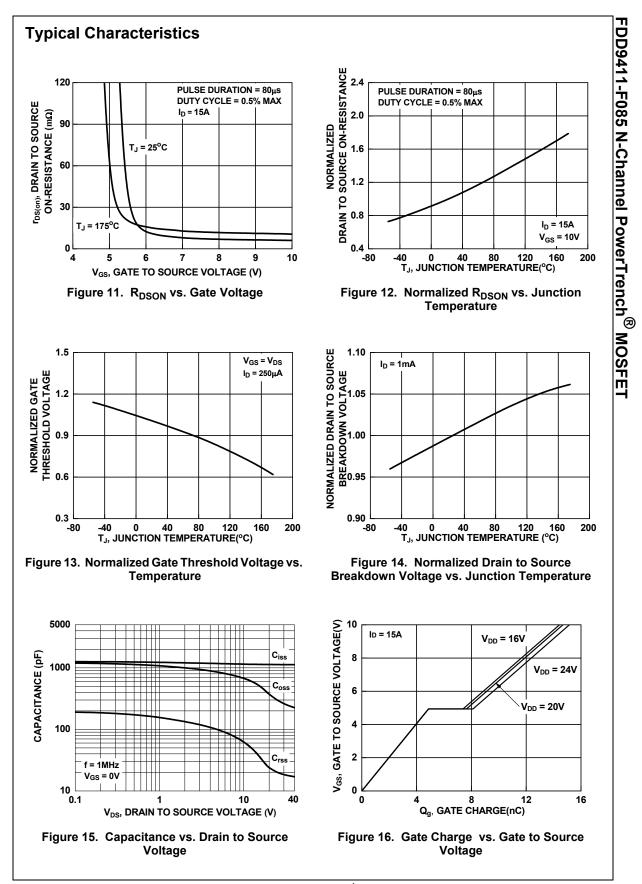
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Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	racteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V		40	-	-	V
I _{DSS}	Drain-to-Source Leakage Current	V _{DS} =40V,		-	-	1	μA
	-		$T_{\rm J} = 175^{\rm o}C \ ({\rm Note} \ 4)$	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	V_{GS} = ±20V		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D	_D = 250μA	2.0	3.4	4.0	V
_	Drain to Source On Resistance	I _D = 15A,	$T_{J} = 25^{\circ}C$	-	6.2	7.8	mΩ
R _{DS(on)}	Drain to Source On Resistance	V _{GS} = 10V	T _J = 175 ^o C (Note 4)	-	11.2	14	mΩ
Dynami	c Characteristics						
C _{iss}	Input Capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	1080	-	pF
C _{oss}	Output Capacitance			-	340	-	pF
C _{rss}	Reverse Transfer Capacitance			-	22	-	pF
R _g	Gate Resistance	f = 1MHz		-	2.6	-	Ω
Q _{g(ToT)}	Total Gate Charge	V _{GS} = 0 to 10	V V _{DD} = 32V	-	15	22.5	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	/ I _D = 15A	-	2	-	nC
Q _{gs}	Gate-to-Source Gate Charge			-	5.3	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	2.8	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	24	ns
t _{d(on)}	Turn-On Delay			-	8.7	-	ns
t _r	Rise Time		V _{DD} = 20V, I _D = 15A,		7.2	-	ns
t _{d(off)}	Turn-Off Delay	V_{GS} = 10V, R_{GEN} = 6 Ω		-	15.8	-	ns
t _f	Fall Time			-	4.4	-	ns
t _{off}	Turn-Off Time		-	-	30	ns	
Drain-S	ource Diode Characteristics						
Var	Source_to_Drain Diado Voltago	I _{SD} = 15A, V _{GS} = 0V		-	-	1.25	V
V _{SD}	Source-to-Drain Diode Voltage	I _{SD} = 7.5A, V _{GS} = 0V		-	-	1.2	V
t _{rr}	Reverse-Recovery Time	V _{DD} = 32V, I _F = 15A,		-	35	53	ns
Q _{rr}	Reverse-Recovery Charge	dl _{SD} /dt = 100A/µs		-	20	30	nC





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